

TC74VHC132F, TC74VHC132FN, TC74VHC132FT, TC74VHC132FK

Quad 2-Input Schmitt NAND Gate

The TC74VHC132 is an advanced high speed CMOS 2-INPUT SCHMITT NAND GATE fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Pin configuration and function are the same as the TC74VHC00 but the inputs have hysteresis and with its schmitt trigger function, the TC74VHC132 can be used as a line receivers which will receive slow input signals.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3 V systems and two supply systems such as battery back up.

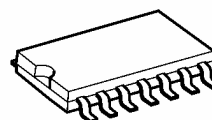
This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: $t_{pd} = 4.9 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \mu\text{A (max)}$ at $T_a = 25^\circ\text{C}$
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC (opr)} = 2 \text{ to } 5.5 \text{ V}$
- Low noise: $V_{OLP} = 0.8 \text{ V (max)}$
- Pin and function compatible with 74ALS132

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74VHC132F



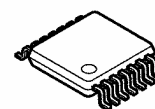
SOP14-P-300-1.27A

TC74VHC132FN



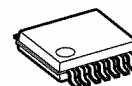
SOL14-P-150-1.27

TC74VHC132FT



TSSOP14-P-0044-0.65A

TC74VHC132FK

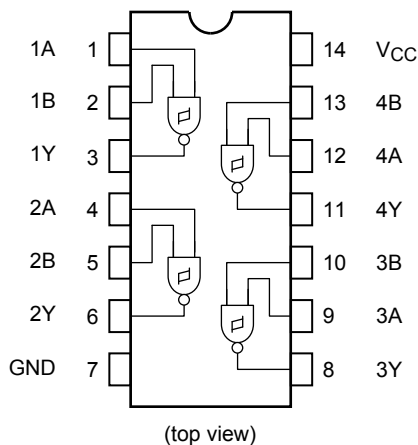


VSSOP14-P-0030-0.50

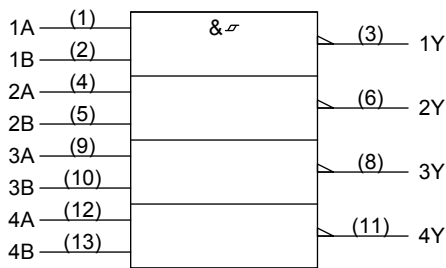
Weight

SOP14-P-300-1.27A	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)

Pin Assignment



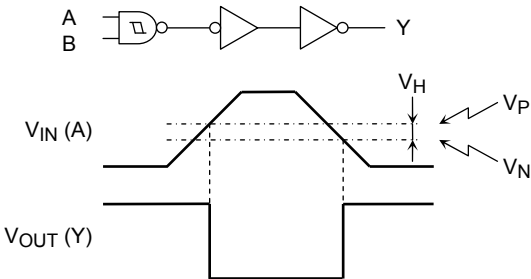
IEC Logic Symbol



Truth Table

A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

System Diagram, Waveform



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V _{CC} (V)	Ta = 25°C			Ta = -40 to 85°C		Unit
					Min	Typ.	Max	Min	Max	
Positive threshold voltage	V _P	—		3.0 4.5 5.5	— — —	— — —	2.20 3.15 3.85	— — —	2.20 3.15 3.85	V
Negative threshold voltage	V _N	—		3.0 4.5 5.5	0.90 1.35 1.65	— — —	— — —	0.90 1.35 1.65	— — —	V
Hysteresis output voltage	V _H	—		3.0 4.5 5.5	0.30 0.40 0.50	— — —	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 µA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
			I _{OH} = -4 mA I _{OH} = -8 mA	4.5	4.4	4.5	—	4.4	—	
				3.0	2.58	—	—	2.48	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 µA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
			I _{OL} = 4 mA I _{OL} = 8 mA	4.5	—	0.0	0.1	—	0.1	
				3.0	—	—	0.36	—	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	µA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	2.0	—	20.0	µA

AC Characteristics (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
			VCC (V)	CL (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time	t _{pLH} t _{pHL}	—	3.3 ± 0.3	15	—	7.6	11.9	1.0	14.0	ns
				50	—	10.1	15.4	1.0	17.5	
			5.0 ± 0.5	15	—	4.9	7.7	1.0	9.0	
				50	—	6.4	9.7	1.0	11.0	
Input capacitance	C _{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C _{PD}	(Note)			—	16	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

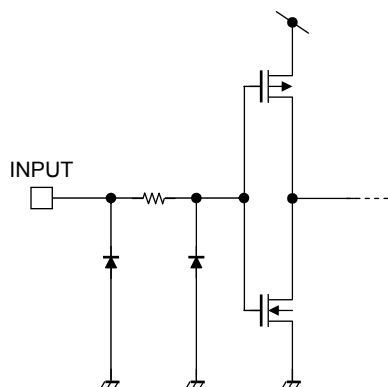
Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V _{CC} (V)	Typ.	Max	
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.3	-0.8	V
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	—	1.5	V

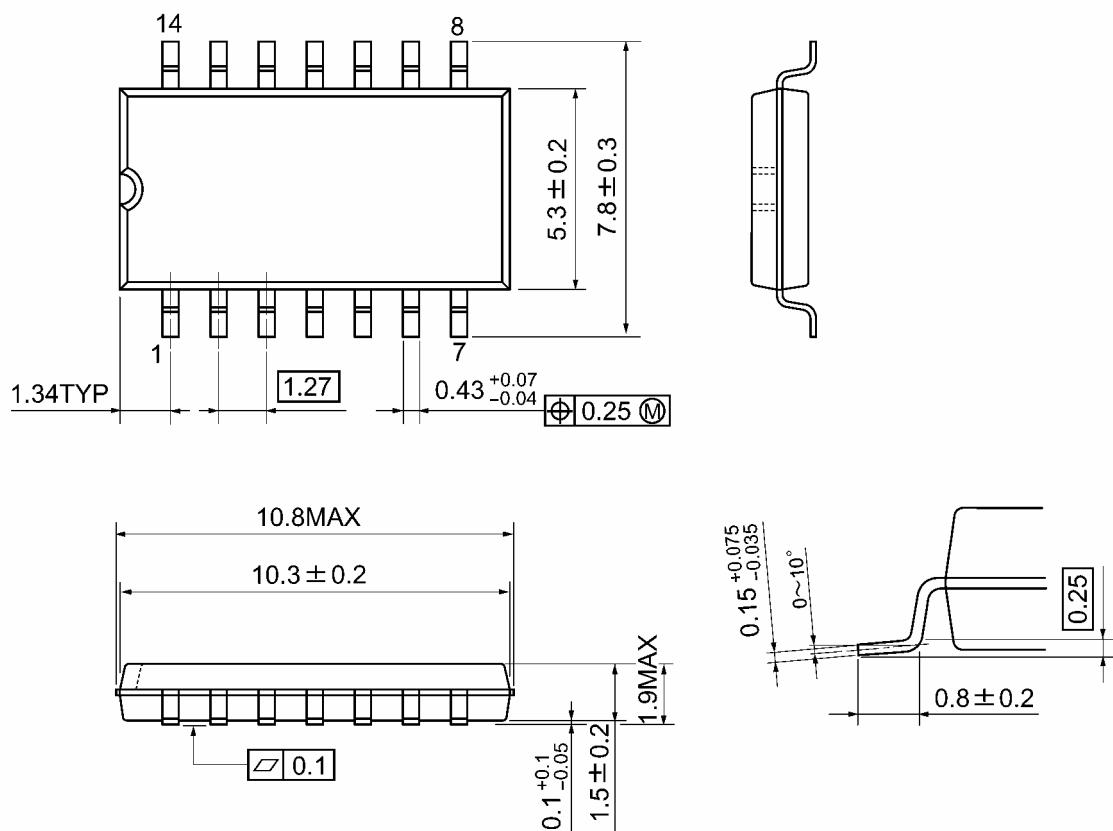
Input Equivalent Circuit



Package Dimensions

SOP14-P-300-1.27A

Unit: mm

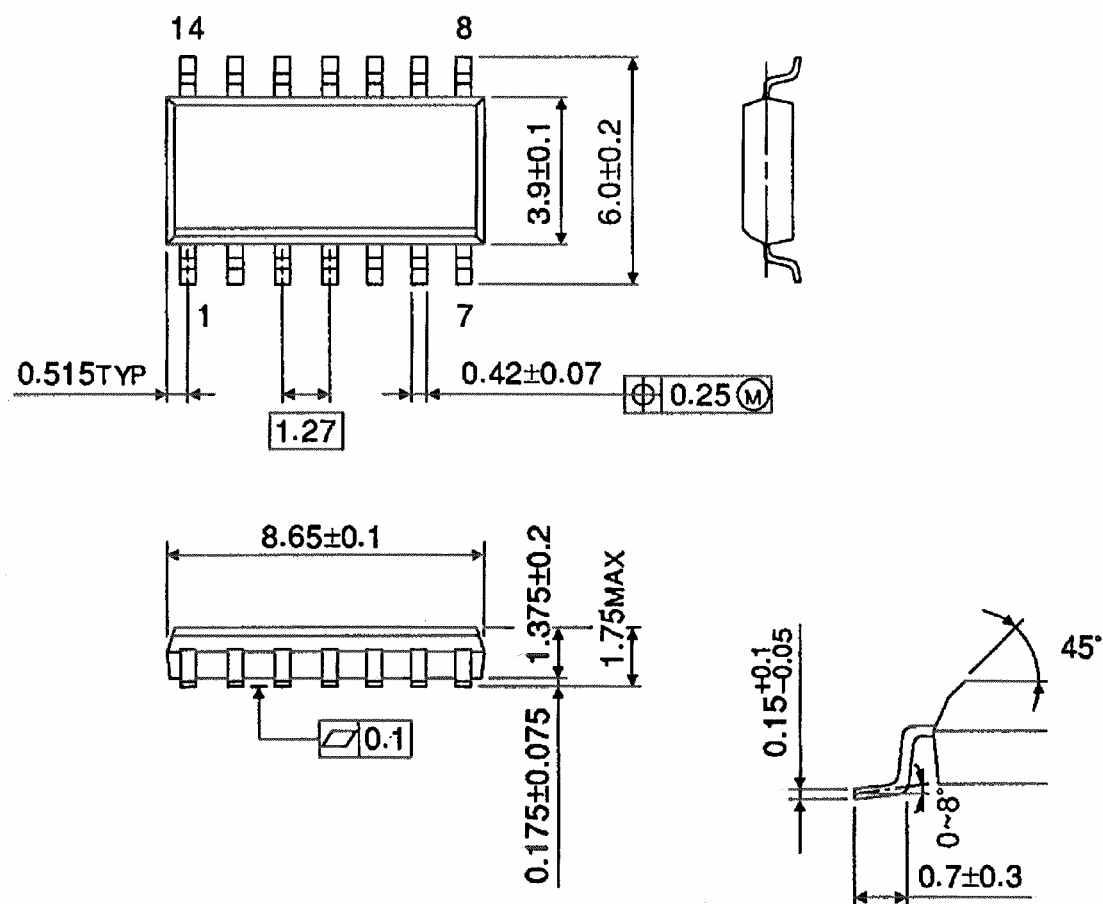


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



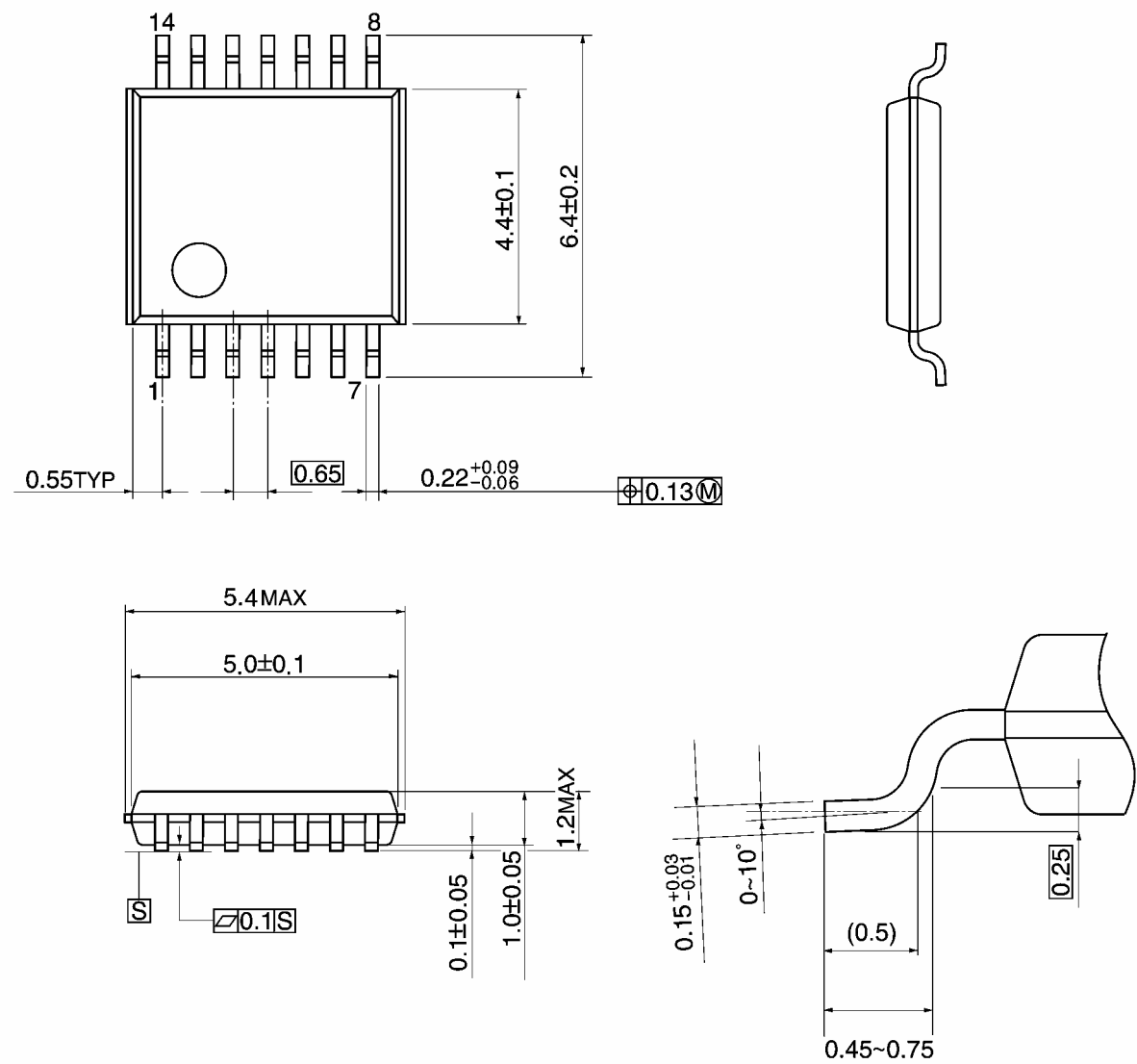
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm

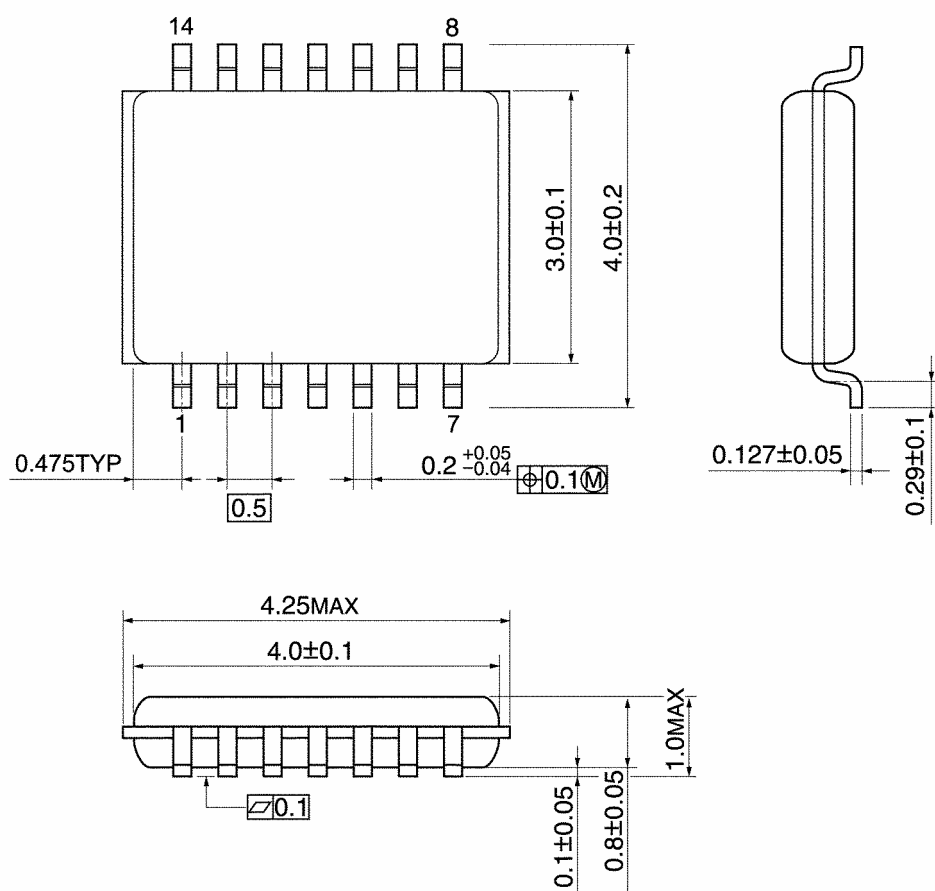


Weight: 0.06 g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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